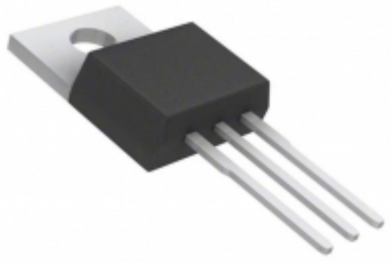




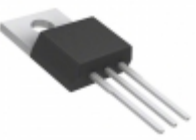
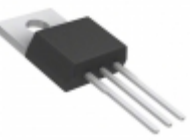



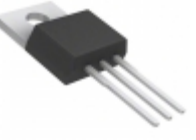
| | |
|--|--|
|   | <h2 style="color: red;">FDP083N15A</h2> <p>Hersteller-Teilenummer: FDP083N15A</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 150V TO-220-3</p> <p>Datenblätter:  FDP083N15A.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 23990 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  <p><small>YIC International Co., Limited.</small></p> | |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|--|---|
| Teilenummer | FDP083N15A |
| Hersteller | Fairchild/ON Semiconductor |
| Beschreibung | MOSFET N-CH 150V TO-220-3 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 23990 pcs Stock |
| Serie | PowerTrench® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Through Hole |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220-3 |
| Verlustleistung (max) | 294W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 150V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 83A (Tc) |
| Rds On (Max) @ Id, Vgs | 8.3 mOhm @ 75A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 84nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 6040pF @ 25V |
| Verpackung | Tube |

FDP083N15A ist neu im Original, Suche FDP083N15A Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDP083N15A Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FDP083N15A: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|---|--|---|
|  <p>FDP085N10A Fairchild/ON Semiconductor MOSFET N-CH 100V TO-220-3</p> |  <p>FDP075N15A-F102 AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 130A TO-220-3</p> |  <p>FDP083N15A AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V TO-220-3</p> |  <p>FDP075N15A_F102 Fairchild/ON Semiconductor MOSFET N-CH 150V 130A TO-220-3</p> |
|  <p>FDP075N15A AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 130A TO-220-3</p> |  <p>FDP070AN06AO FAIRCHILD FDP070AN06AO FAIRCHILD</p> |  <p>FDP075N15A Fairchild/ON Semiconductor MOSFET N-CH 150V 130A TO-220-3</p> |  <p>FDP083N15A-F102 AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 83A TO220-3</p> |

heiße Teile

Mehr

| | | | | |
|---|--|--|--|--|
|  FDP047AN08AO |  FDP047N08 |  FDP047N08 |  FDP047N08AO |  FDP047N10 |
|  FDP047N10 |  FDP050AN06AO |  FDP050AN06AO |  FDP050AN06AO |  FDP053N08B |
|  FDP053N08B_F102 |  FDP054N10 |  FDP054N10 |  FDP060AN08AO |  FDP060AN08AO |
|  FDP060AN08AO |  FDP060N08AO |  FDP060N08AO |  FDP068AN08AO |  FDP070AN06AO |
|  FDP070AN06AO |  FDP070AN06AO |  FDP075N15A |  FDP075N15A |  FDP083N15A |
|  FDP083N15A_F102 |  FDP085N10A |  FDP085N10A |  FDP085N10A_F102 |  FDP090N10 |
|  FDP090N10 |  FDP100N10 |  FDP100N10 |  FDP10AN06AO |  FDP10AN06AO |
|  FDP10AN06AO |  FDP10N60NZ |  FDP10N60NZ |  FDP120AN15AO |  FDP120AN15AO |
|  FDP120AN15AO |  FDP120N10 |  FDP120N10 |  FDP12N50 |  FDP12N50 |
|  FDP12N50NZ |  FDP12N50NZ |  FDP12N60NZ |  FDP12N60NZ |  FDP13AN06AO |

Contact us: Info@Y-IC.com

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